

MMIC VCO WITH HALF FREQUENCY OUTPUT 9.05 - 10.15 GHz



Typical Applications

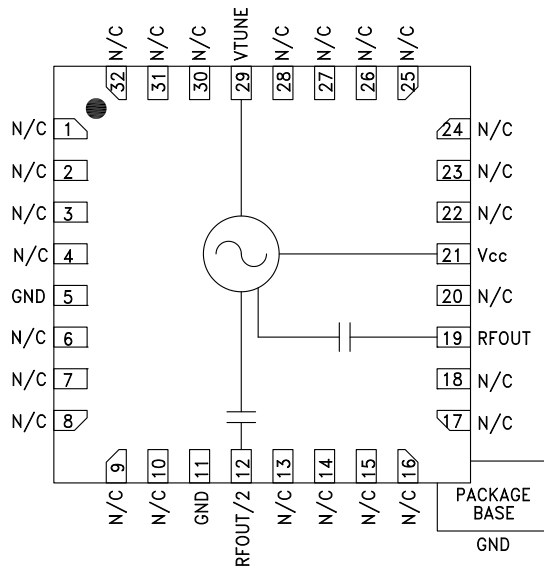
Low noise MMIC VCO w/Half Frequency, for:

- VSAT Radio
- Point to Point/Multi-Point Radio
- Test Equipment & Industrial Controls
- Military End-Use

Features

- Dual Output: $F_o = 9.05 - 10.15$ GHz
 $F_o/2 = 4.525 - 5.075$ GHz
- Pout: +13 dBm
- Phase Noise: -115 dBc/Hz @100 kHz Typ.
- No External Resonator Needed
- 32 Lead 5x5mm SMT Package: 25mm²

Functional Diagram



General Description

The HMC511LP5 & HMC511LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC511LP5 & HMC511LP5E integrate resonators, negative resistance devices, varactor diodes and feature a half frequency output. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +13 dBm typical from a +5V supply. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{cc} = +5\text{V}$

| Parameter | Min. | Typ. | Max. | Units |
|---|------|---------------|------|-----------------------|
| Frequency Range | | 9.05 - 10.15 | | GHz |
| | | 4.525 - 5.075 | | GHz |
| Power Output | | | | |
| | +9 | | +16 | dBm |
| | +5 | | +11 | dBm |
| SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5\text{V}$ @ RFOUT | | -115 | | dBc/Hz |
| Tune Voltage | 2 | | 13 | V |
| Supply Current (I_{cc}) ($V_{cc} = +5.0\text{V}$) | 200 | 265 | 300 | mA |
| Tune Port Leakage Current ($V_{tune} = 13\text{V}$) | | | 10 | μA |
| Output Return Loss | | 2 | | dB |
| Harmonics/Subharmonics | | | | |
| | 1/2 | 38 | | dBc |
| | 2nd | 15 | | dBc |
| | 3rd | 30 | | dBc |
| Pulling (into a 2.0:1 VSWR) | | 8 | | MHz pp |
| Pushing @ $V_{tune} = 5\text{V}$ | | 15 | | MHz/V |
| Frequency Drift Rate | | 0.9 | | MHz/ $^\circ\text{C}$ |

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HMC511* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC511LP5 Evaluation Board.

DOCUMENTATION

Data Sheet

- HMC511 Data Sheet

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: 32L 5x5mm QFN Package (QTR: 10009 REV: 05)
- Package/Assembly Qualification Test Report: LP3, LP4, LP5 & LP5G (QTR: 2014-00145)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (QTR: 2013-00228)

Technical Articles

- High Performance SiGe PLLs Pair with Low Phase Noise GaAs VCOs for Microwave Radio

DESIGN RESOURCES

- HMC511 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC511 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

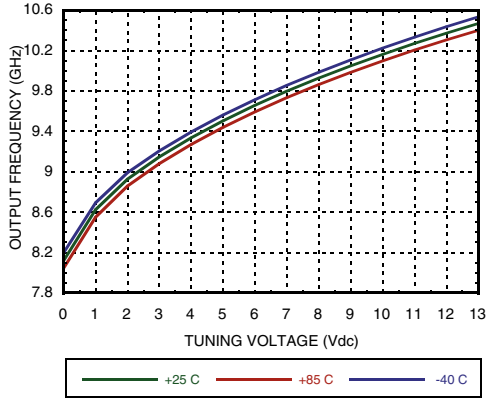
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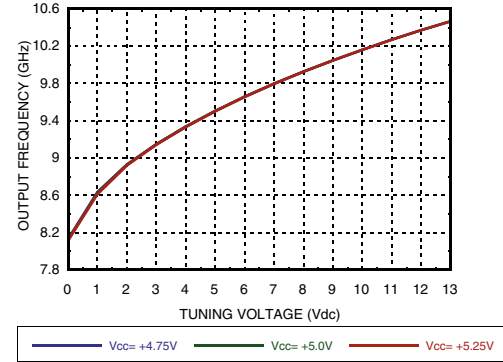
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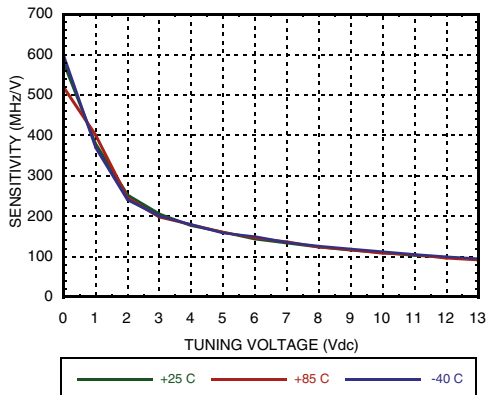
Frequency vs. Tuning Voltage



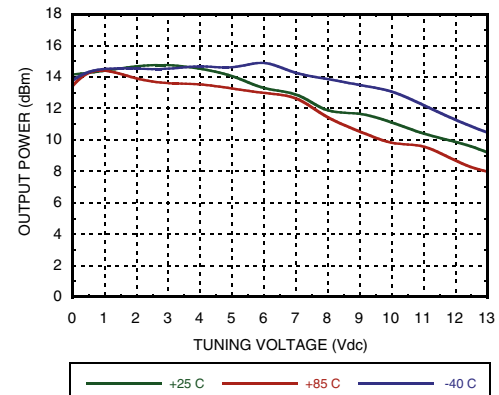
Frequency vs. Tuning Voltage, T = 25C



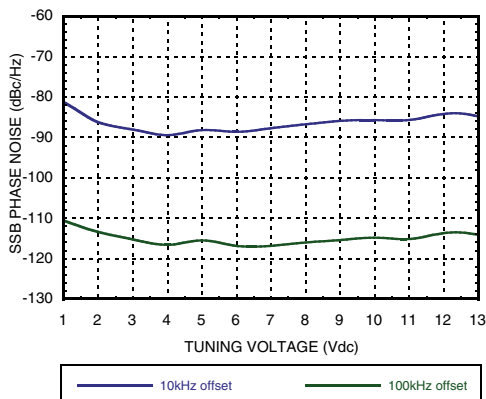
Sensitivity vs. Tuning Voltage



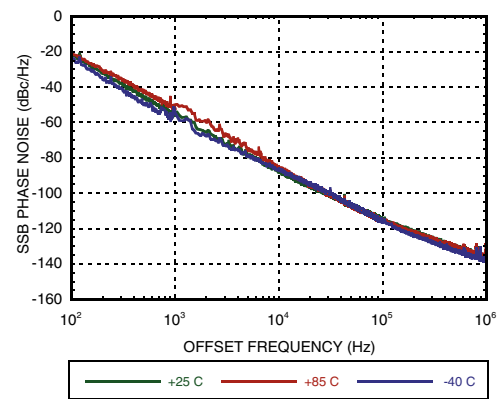
Output Power vs. Tuning Voltage



SSB Phase Noise vs. Tuning Voltage



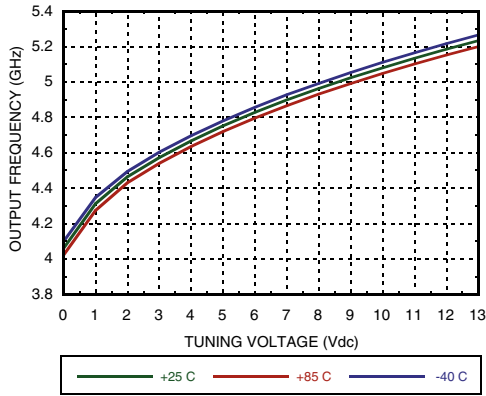
SSB Phase Noise @ Vtune = +5V



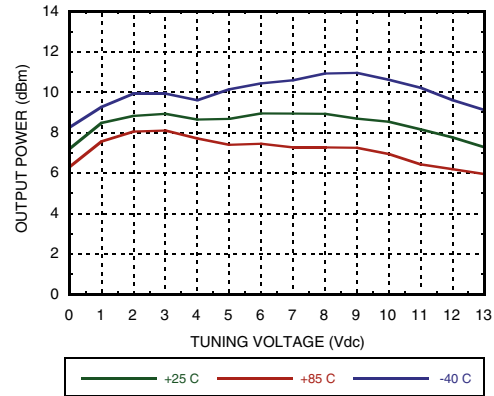
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RFOUT/2 Frequency vs. Tuning Voltage



RFOUT/2 Output Power vs. Tuning Voltage



Absolute Maximum Ratings

| | |
|-----------------------|----------------|
| Vcc | +5.5 Vdc |
| Vtune | 0 to +15V |
| Storage Temperature | -65 to +150 °C |
| ESD Sensitivity (HBM) | Class 1A |

Reliability Information

| | |
|--|---------------|
| Junction Temperature To Maintain 1 Million Hour MTTF | 135 °C |
| Nominal Junction Temperature (T = +85 °C) | 126.9 °C |
| Thermal Resistance (junction to ground paddle) | 31.6 °C/W |
| Operating Temperature | -40 to +85 °C |



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Typical Supply Current vs. Vcc

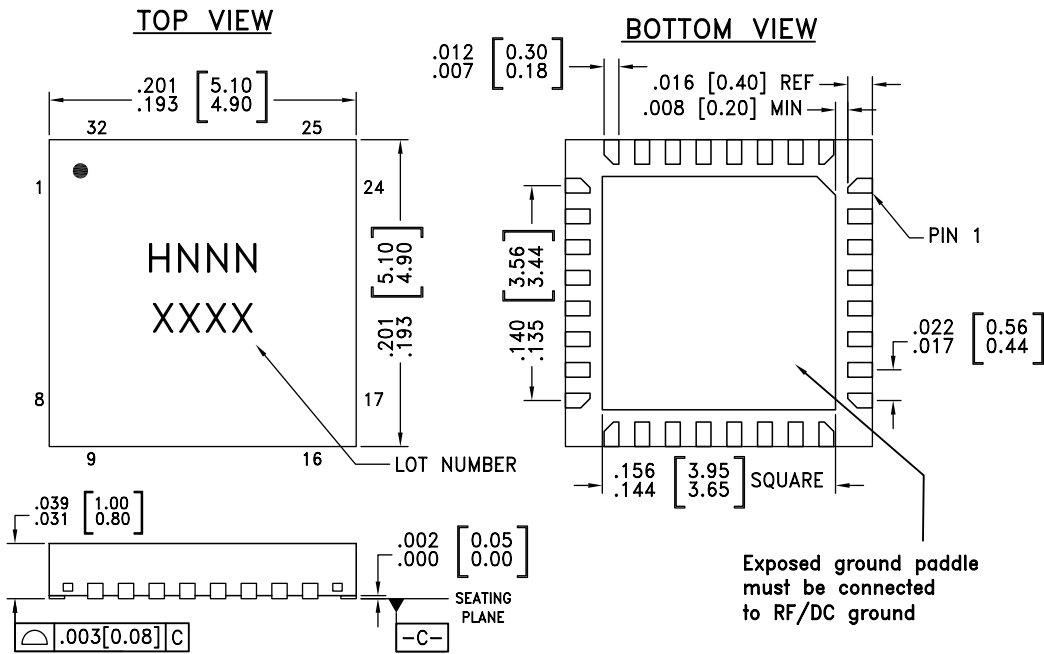
| Vcc (V) | Icc (mA) |
|---------|----------|
| 4.75 | 245 |
| 5.0 | 265 |
| 5.25 | 285 |

Note: VCO will operate over full voltage range shown above.

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Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[3] |
|-------------|---|---------------|---------------------|--------------------------------|
| HMC511LP5 | Low Stress Injection Molding Plastic | Sn/Pb Solder | MSL3 ^[1] | H511 XXXX |
| HMC511LP5E | RoHS-compliant Low Stress Injection Molding Plastic | 100% matte Sn | MSL3 ^[2] | H511 XXXX |

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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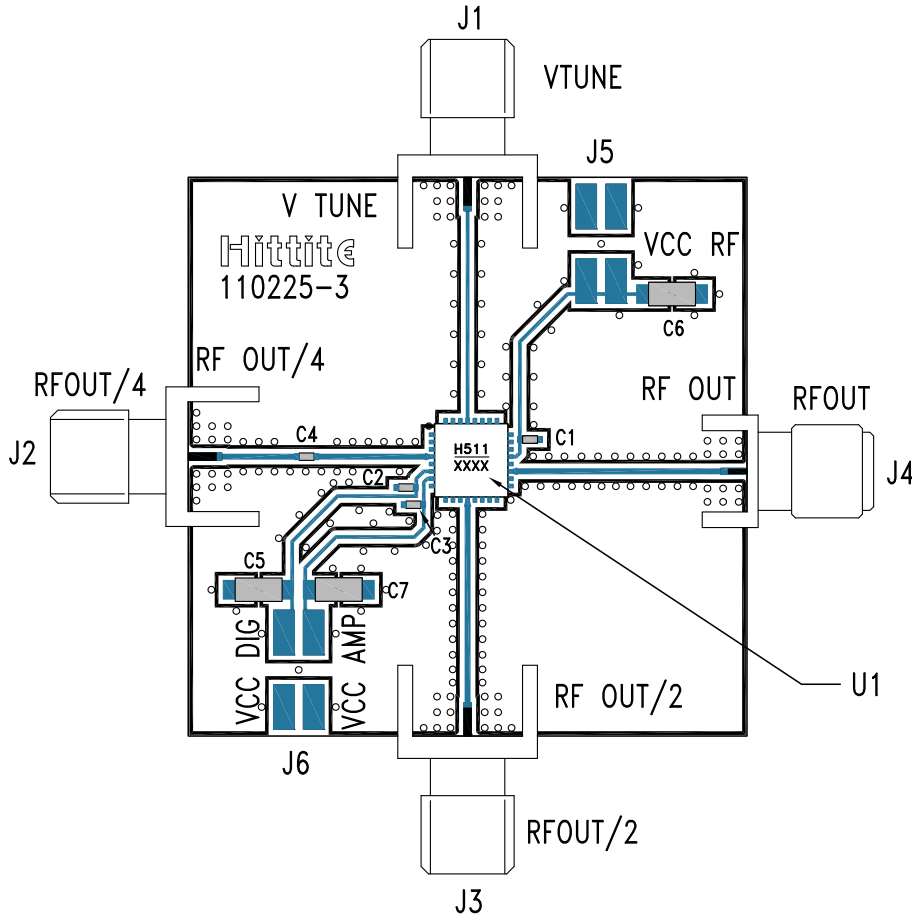
Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|--|----------|---|---------------------|
| 1 - 4, 6 - 10, 13 - 18, 20, 22 - 28, 30 - 32 | N/C | No Connection. These pins may be connected to RF/DC ground. Performance will not be affected. | |
| 12 | RFOUT/2 | Half frequency output (AC coupled). | |
| 19 | RFOUT | RF output (AC coupled). | |
| 21 | Vcc | Supply Voltage, +5V | |
| 29 | VTUNE | Control Voltage Input. Modulation port bandwidth dependent on drive source impedance. | |
| 5, 11 Paddle | GND | Package bottom has an exposed metal paddle that must be connected to RF/DC ground. | |

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Evaluation PCB



List of Materials for Evaluation PCB 110227 [1]

| Item | Description |
|---------|--------------------------------|
| J1 - J4 | PCB Mount SMA RF Connector |
| J5 | 2 mm DC Header |
| C1 - C3 | 100 pF Capacitor, 0402 Pkg. |
| C4 | 1,000 pF Capacitor, 0402 Pkg. |
| C5 - C7 | 2.2 μ F Tantalum Capacitor |
| U1 | HMC511LP5(E) VCO |
| PCB [2] | 110225 Eval Board |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.